

Data sheet acquired from Harris Semiconductor SCHS150C

September 1997 - Revised October 2003

High-Speed CMOS Logic 8-Input Multiplexer

Features

- · Complementary Data Outputs
- · Buffered Inputs and Outputs
- Fanout (Over Temperature Range)
 - Standard Outputs...... 10 LSTTL Loads
 - Bus Driver Outputs 15 LSTTL Loads
- Wide Operating Temperature Range ... -55°C to 125°C
- Balanced Propagation Delay and Transition Times
- Significant Power Reduction Compared to LSTTL Logic ICs
- · Alternate Source is Philips/Signetics
- HC Types
 - 2V to 6V Operation
 - High Noise Immunity: N_{IL} = 30%, N_{IH} = 30% of V_{CC} at V_{CC} = 5V
- HCT Types
 - 4.5V to 5.5V Operation
 - Direct LSTTL Input Logic Compatibility,
 V_{IL}= 0.8V (Max), V_{IH} = 2V (Min)
 - CMOS Input Compatibility, I $_I \leq 1 \mu \text{A}$ at $\text{V}_{\mbox{OL}}, \, \text{V}_{\mbox{OH}}$

Description

The 'HC151 and 'HCT151 are single 8-channel digital multiplexers having three binary control inputs, S0, S1 and S2 and an active low enable (\overline{E}) input. The three binary signals select 1 of 8 channels. Outputs are both inverting (\overline{Y}) and non-inverting (Y).

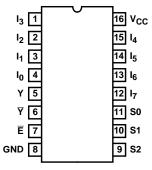
Ordering Information

PART NUMBER	TEMP. RANGE (°C)	PACKAGE
CD54HC151F3A	-55 to 125	16 Ld CERDIP
CD54HCT151F3A	-55 to 125	16 Ld CERDIP
CD74HC151E	-55 to 125	16 Ld PDIP
CD74HC151M	-55 to 125	16 Ld SOIC
CD74HC151MT	-55 to 125	16 Ld SOIC
CD74HC151M96	-55 to 125	16 Ld SOIC
CD74HCT151E	-55 to 125	16 Ld PDIP
CD74HCT151M	-55 to 125	16 Ld SOIC
CD74HCT151MT	-55 to 125	16 Ld SOIC
CD74HCT151M96	-55 to 125	16 Ld SOIC

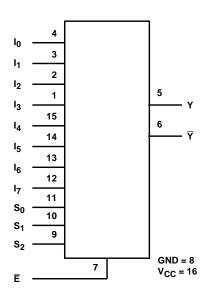
NOTE: When ordering, use the entire part number. The suffix 96 denotes tape and reel. The suffix T denotes a small-quantity reel of 250.

Pinout

CD54HC151, CD54HCT151 (CERDIP) CD74HC151, CD74HCT151 (PDIP, SOIC) TOP VIEW



Functional Diagram



TRUTH TABLE

SEL	ECT INP	UTS				DATA I	NPUTS				ENABLE OUT		PUT
S2	S1	S0	10	ĪĪ	I2	13	14	15	16	17	Ē	Ÿ	Υ
Х	Х	Х	Х	Х	Х	Х	Х	Х	Х	Х	Н	Н	L
L	L	L	L	Х	Х	Х	Х	Х	Х	Х	L	Н	L
L	L	L	Н	Х	Х	Х	Х	Х	Х	Х	L	L	Н
L	L	Н	Х	L	Х	Х	Х	Х	Х	Х	L	Н	L
L	L	Н	Х	Н	Х	Х	Х	Х	Х	Х	L	L	Н
L	Н	L	Х	Х	L	Х	Х	Х	Х	Х	L	Н	L
L	Н	L	Х	Х	Н	Х	Х	Х	Х	Х	L	L	Н
L	Н	Н	Х	Х	Х	L	Х	Х	Х	Х	L	Н	L
L	Н	Н	Х	Х	Х	Н	Х	Х	Х	Х	L	L	Н
Н	L	L	Х	Х	Х	Х	L	Х	Х	Х	L	Н	L
Н	L	L	Х	Х	Х	Х	Н	Х	Х	Х	L	L	Н
Н	L	Н	Х	Х	Х	Х	Х	L	Х	Х	L	Н	L
Н	L	Н	Х	Х	Х	Х	Х	Н	Х	Х	L	L	Н
Н	Н	L	Х	Х	Х	Х	Х	Х	L	Х	L	Н	L
Н	Н	L	Х	Х	Х	Х	Х	Х	Н	Х	L	L	Н
Н	Н	Н	Х	Х	Х	Х	Х	Х	Х	L	L	Н	L
Н	Н	Н	Х	Х	Х	Х	Х	Х	Х	Н	L	L	Н
H = High	H = High Voltage Level, L = Low Voltage Level, X = Don't Care												

Absolute Maximum Ratings

Thermal Information

Thermal Resistance (Typical, Note 1)	θ_{JA} (oC/W)
E (PDIP) Package	67
M (SOIC) Package	
Maximum Junction Temperature	
Maximum Storage Temperature Range	65°C to 150°C
Maximum Lead Temperature (Soldering 10s)	300°C
(SOIC - Lead Tips Only)	

Operating Conditions

Temperature Range (T _A)55 ⁰ C to 125 ⁰	C,
Supply Voltage Range, V _{CC}	
HC Types2V to 6	۷
HCT Types	ί۷
DC Input or Output Voltage, V _I , V _O 0V to V _C	СС
Input Rise and Fall Time	
2V	x)
4.5V 500ns (Ma	x)
6V	x)

CAUTION: Stresses above those listed in "Absolute Maximum Ratings" may cause permanent damage to the device. This is a stress only rating and operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied.

NOTE:

1. The package thermal impedance is calculated in accordance with JESD 51-7.

DC Electrical Specifications

			TEST CONDITIONS			25°C		-40°C 1	O 85°C	-55°C T	O 125°C												
PARAMETER	SYMBOL	V _I (V)	I _O (mA)	v _{cc} (v)	MIN	TYP	MAX	MIN	MAX	MIN	MAX	UNITS											
HC TYPES																							
High Level Input	V _{IH}	-	-	2	1.5	-	-	1.5	-	1.5	-	V											
Voltage				4.5	3.15	-	-	3.15	-	3.15	-	V											
				6	4.2	-	-	4.2	-	4.2	-	V											
Low Level Input	V _{IL}	-	-	2	-	-	0.5	-	0.5	-	0.5	V											
Voltage				4.5	-	-	1.35	-	1.35	-	1.35	V											
				6	-	-	1.8	-	1.8	-	1.8	V											
High Level Output	VoH	V _{IH} or V _{IL}	-0.02	2	1.9	-	-	1.9	-	1.9	-	V											
Voltage CMOS Loads			-0.02	4.5	4.4	-	-	4.4	-	4.4	-	V											
			-0.02	6	5.9	-	-	5.9	-	5.9	-	V											
High Level Output	7		-	-	-	-	-	-	-	-	-	V											
Voltage TTL Loads			-4	4.5	3.98	-	-	3.84	-	3.7	-	V											
TTE LOGUS			-5.2	6	5.48	-	-	5.34	-	5.2	-	V											
Low Level Output	V _{OL}	V _{IH} or V _{IL}	0.02	2	-	-	0.1	-	0.1	-	0.1	V											
Voltage CMOS Loads			0.02	4.5	-	-	0.1	-	0.1	-	0.1	V											
OWIGO Edads		f									-		<u></u>	0.02	6	-	-	0.1	-	0.1	-	0.1	V
Low Level Output	7		-	-	-	-	-	-	-	-	-	V											
Voltage TTL Loads			4	4.5	-	-	0.26	-	0.33	-	0.4	V											
I I L Loads			5.2	6	-	-	0.26	-	0.33	-	0.4	V											
Input Leakage Current	IĮ	V _{CC} or GND	-	6	-	-	±0.1	-	±1	-	±1	μΑ											
Quiescent Device Current	lcc	V _{CC} or GND	0	6	-	-	8	-	80	-	160	μΑ											

DC Electrical Specifications (Continued)

		TES CONDI		v _{cc}		25°C		-40°C 1	O 85°C	-55°C TO 125°C		
PARAMETER	SYMBOL	V _I (V)	I _O (mA)	(V)	MIN	TYP	MAX	MIN	MAX	MIN	MAX	UNITS
HCT TYPES												
High Level Input Voltage	V _{IH}	-	-	4.5 to 5.5	2	-	-	2	-	2	-	V
Low Level Input Voltage	V _{IL}	-	-	4.5 to 5.5	-	-	0.8	-	0.8	-	0.8	V
High Level Output Voltage CMOS Loads	V _{OH}	V _{IH} or V _{IL}	-0.02	4.5	4.4	-	-	4.4	-	4.4	-	V
High Level Output Voltage TTL Loads			-4	4.5	3.98	-	-	3.84	-	3.7	-	V
Low Level Output Voltage CMOS Loads	V _{OL}	V _{IH} or V _{IL}	0.02	4.5	-	-	0.1	-	0.1	-	0.1	V
Low Level Output Voltage TTL Loads			4	4.5	-	=	0.26	-	0.33	-	0.4	V
Input Leakage Current	lį	V _{CC} and GND	0	5.5	-		±0.1	-	±1	-	±1	μА
Quiescent Device Current	Icc	V _{CC} or GND	0	5.5	-	-	8	-	80	-	160	μА
Additional Quiescent Device Current Per Input Pin: 1 Unit Load	ΔI _{CC} (Note 2)	V _{CC} -2.1	-	4.5 to 5.5	-	100	360	-	450	-	490	μА

NOTE:

HCT Input Loading Table

INPUT	UNIT LOADS
Select	1.5
Data	0.45
Enable	0.3

NOTE: Unit Load is ΔI_{CC} limit specified in DC Electrical Table, e.g., 360µA max at $25^{\rm o}C.$

Switching Specifications Input t_r , $t_f = 6ns$

		TEST		25°C			-40°C TO 85°C		-55°C TO 125°C		
PARAMETER	SYMBOL	CONDITIONS	V _{CC} (V)	MIN	TYP	MAX	MIN	MAX	MIN	MAX	UNITS
HC TYPES											
Propagation Delay (Figure 1)	t _{PLH} , t _{PHL}	C _L = 50pF	2	-	-	170	-	215	-	255	ns
Any Data Input to Y			4.5	-	-	34	-	43	-	51	ns
		C _L =15pF	5	-	14	-	-	-	-	-	ns
		C _L = 50pF	6	i	-	29	-	37	-	43	ns

^{2.} For dual-supply systems theoretical worst case ($V_I = 2.4V$, $V_{CC} = 5.5V$) specification is 1.8mA.

Switching Specifications Input $t_{\rm f},\,t_{\rm f}=6{\rm ns}$ (Continued)

		TEST			25°C			С ТО °С		C TO 5°C	
PARAMETER	SYMBOL	CONDITIONS	V _{CC} (V)	MIN	TYP	MAX	MIN	MAX	MIN	MAX	UNITS
Any Data Input to \overline{Y}	t _{PLH} , t _{PHL}	C _L = 50pF	2	-	-	185	-	230	-	280	ns
			4.5	-	-	37	-	46	-	56	ns
		C _L =15pF	5	-	15	-	-	-	-	-	ns
		C _L = 50pF	6	-	-	31	-	39	-	48	ns
Any Select to Y	t _{PLH} , t _{PHL}	C _L = 50pF	2	-	-	185	-	230	-	280	ns
			4.5	-	-	37	-	46	-	56	ns
		C _L =15pF	5	-	15	-	-	-	-	-	ns
		C _L = 50pF	6	-	-	31	-	39	-	48	ns
Any Select to \overline{Y}	t _{PLH} , t _{PHL}	C _L = 50pF	2	-	-	205	-	255	-	310	ns
			4.5	-	-	41	-	51	-	62	ns
		C _L =15pF	5	-	17	-	-	-	-	-	ns
		C _L = 50pF	6	-	-	35	-	43	-	53	ns
Enable to Y	t _{PLH} , t _{PHL}	C _L = 50pF	2	-	-	140	-	175	-	210	ns
			4.5	-	-	28	-	35	-	42	ns
		C _L =15pF	5	-	11	-	-	-	-	-	ns
		C _L = 50pF	6	-	-	24	-	30	-	36	ns
Enable to \overline{Y}	t _{PLH} , t _{PHL}	C _L = 50pF	2	-	-	145	-	180	-	220	ns
			4.5	-	-	29	-	36	-	44	ns
		C _L =15pF	5	-	12	-	-	-	-	-	ns
		C _L = 50pF	6	-	-	25	-	31	-	38	ns
Output Transition Time	t _{TLH} , t _{THL}	C _L = 50pF	2	-	-	75	-	95	-	110	ns
(Figure 1)			4.5	-	-	15	-	19	-	22	ns
			6	-	-	13	-	16	-	19	ns
Input Capacitance	C _{IN}	-	-	-	-	10	-	10	-	10	pF
Power Dissipation Capacitance (Notes 3, 4)	C _{PD}	-	5	-	59	-	-	-	-	-	pF
HCT TYPES	<u> </u>		•		•	•		ı			
Propagation Delay (Figure 2) Any Data Input to Y	t _{PLH} , t _{PHL}	C _L = 50pF	4.5	-	_	38	-	48	-	57	ns
		C _L =15pF	5	-	16	-	-		-	-	ns
Any Data Input to \overline{Y}	t _{PLH} , t _{PHL}	C _L = 50pF	4.5	-	-	36	-	45	-	54	ns
		C _L =15pF	5	-	15	-	-	-	-	-	ns
Any Select to Y	t _{PLH} , t _{PHL}	C _L = 50pF	4.5	-		41	-	51	-	62	ns
		C _L =15pF	5	-	17	-	-	-	-	-	ns
Any Select to \overline{Y}	t _{PLH} , t _{PHL}	C _L = 50pF	4.5	-	-	43	-	54	-	65	ns
		C _L =15pF	5	-	18	-	-	-	-	-	ns
Enable to Y	t _{PLH} , t _{PHL}	C _L = 50pF	4.5	-	-	29	-	36	-	44	ns
		C _L =15pF	5	-	12	-	-	-	-	-	ns

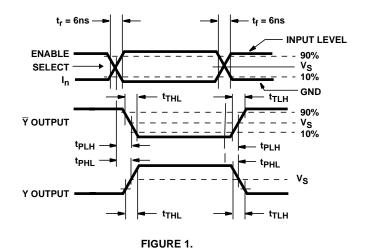
Switching Specifications Input t_r , $t_f = 6ns$ (Continued)

		TEST			25°C		-40 ⁰ (85		-55°C TO 125°C		
PARAMETER	SYMBOL	CONDITIONS	V _{CC} (V)	MIN	TYP	MAX	MIN	MAX	MIN	MAX	UNITS
Enable to \overline{Y}	C _L = 50pF	C _L = 50pF	4.5	-	-	36	-	46	-	54	ns
	C _L =15pF	C _L =15pF	5	15	-	-	-	-	-	-	ns
Output Transition Time	t _{TLH} , t _{THL}	C _L = 50pF	4.5	-	-	15	-	19	-	22	ns
Input Capacitance	C _{IN}	-	-	-	-	10	-	10	-	10	pF
Power Dissipation Capacitance (Notes 3, 4)	C _{PD}	-	5		58	-	-	-	-	i	pF

NOTES:

- 3. $C_{\mbox{\scriptsize PD}}$ is used to determine the dynamic power consumption, per gate.
- 4. $P_D = V_{CC}^2 f_i (C_{PD} + C_L)$ where f_i = input frequency, C_L = output load capacitance, V_{CC} = supply voltage.

Test Circuit and Waveform







25-Sep-2013

PACKAGING INFORMATION

Orderable Device	Status	Package Type	Package Drawing	Pins	Package Qty	Eco Plan	Lead/Ball Finish	MSL Peak Temp	Op Temp (°C)	Device Marking (4/5)	Samples
5962-9065201MEA	ACTIVE	CDIP	J	16	1	TBD	A42	N / A for Pkg Type	-55 to 125	5962-9065201ME A CD54HCT151F3A	Samples
CD54HC151F3A	ACTIVE	CDIP	J	16	1	TBD	A42	N / A for Pkg Type	-55 to 125	8412801EA CD54HC151F3A	Samples
CD54HCT151F3A	ACTIVE	CDIP	J	16	1	TBD	A42	N / A for Pkg Type	-55 to 125	5962-9065201ME A CD54HCT151F3A	Samples
CD74HC151E	ACTIVE	PDIP	N	16	25	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type	-55 to 125	CD74HC151E	Samples
CD74HC151EE4	ACTIVE	PDIP	N	16	25	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type	-55 to 125	CD74HC151E	Samples
CD74HC151M	ACTIVE	SOIC	D	16	40	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-55 to 125	HC151M	Samples
CD74HC151M96	ACTIVE	SOIC	D	16	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-55 to 125	HC151M	Samples
CD74HC151M96E4	ACTIVE	SOIC	D	16	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-55 to 125	HC151M	Samples
CD74HC151M96G4	ACTIVE	SOIC	D	16	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-55 to 125	HC151M	Samples
CD74HC151ME4	ACTIVE	SOIC	D	16	40	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-55 to 125	HC151M	Samples
CD74HC151MG4	ACTIVE	SOIC	D	16	40	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-55 to 125	HC151M	Samples
CD74HC151MT	ACTIVE	SOIC	D	16	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-55 to 125	HC151M	Samples
CD74HC151MTE4	ACTIVE	SOIC	D	16	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-55 to 125	HC151M	Samples
CD74HC151MTG4	ACTIVE	SOIC	D	16	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-55 to 125	HC151M	Samples
CD74HCT151E	ACTIVE	PDIP	N	16	25	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type	-55 to 125	CD74HCT151E	Samples
CD74HCT151EE4	ACTIVE	PDIP	N	16	25	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type	-55 to 125	CD74HCT151E	Samples





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Orderable Device	Status	Package Type	Package Drawing		Package Qty	Eco Plan	Lead/Ball Finish	MSL Peak Temp	Op Temp (°C)	Device Marking (4/5)	Samples
CD74HCT151M	ACTIVE	SOIC	D	16	40	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-55 to 125	HCT151M	Samples
CD74HCT151M96	ACTIVE	SOIC	D	16	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-55 to 125	HCT151M	Samples
CD74HCT151M96E4	ACTIVE	SOIC	D	16	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-55 to 125	HCT151M	Samples
CD74HCT151M96G4	ACTIVE	SOIC	D	16	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-55 to 125	HCT151M	Samples
CD74HCT151ME4	ACTIVE	SOIC	D	16	40	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-55 to 125	HCT151M	Samples
CD74HCT151MG4	ACTIVE	SOIC	D	16	40	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-55 to 125	HCT151M	Samples
CD74HCT151MT	ACTIVE	SOIC	D	16	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-55 to 125	HCT151M	Samples
CD74HCT151MTE4	ACTIVE	SOIC	D	16	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-55 to 125	HCT151M	Samples
CD74HCT151MTG4	ACTIVE	SOIC	D	16	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-55 to 125	HCT151M	Samples

⁽¹⁾ The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

TBD: The Pb-Free/Green conversion plan has not been defined.

Pb-Free (RoHS): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes. **Pb-Free** (RoHS Exempt): This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

⁽²⁾ Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check http://www.ti.com/productcontent for the latest availability information and additional product content details.

⁽³⁾ MSL. Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.



PACKAGE OPTION ADDENDUM

25-Sep-2013

(4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.

(5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

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In no event shall TI's liability arising out of such information exceed the total purchase price of the TI part(s) at issue in this document sold by TI to Customer on an annual basis.

OTHER QUALIFIED VERSIONS OF CD54HC151, CD54HC151, CD74HC151, CD74HC151:

Catalog: CD74HC151, CD74HCT151

Military: CD54HC151, CD54HCT151

NOTE: Qualified Version Definitions:

Catalog - TI's standard catalog product

Military - QML certified for Military and Defense Applications



TAPE AND REEL INFORMATION





	Dimension designed to accommodate the component width
B0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



*All dimensions are nominal

Device	Package Type	Package Drawing			Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
CD74HC151M96	SOIC	D	16	2500	330.0	16.4	6.5	10.3	2.1	8.0	16.0	Q1
CD74HCT151M96	SOIC	D	16	2500	330.0	16.4	6.5	10.3	2.1	8.0	16.0	Q1





*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)	
CD74HC151M96	SOIC	D	16	2500	333.2	345.9	28.6	
CD74HCT151M96	SOIC	D	16	2500	333.2	345.9	28.6	

14 LEADS SHOWN



- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- C. This package is hermetically sealed with a ceramic lid using glass frit.
- D. Index point is provided on cap for terminal identification only on press ceramic glass frit seal only.
- E. Falls within MIL STD 1835 GDIP1-T14, GDIP1-T16, GDIP1-T18 and GDIP1-T20.

N (R-PDIP-T**)

PLASTIC DUAL-IN-LINE PACKAGE

16 PINS SHOWN



- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- Falls within JEDEC MS-001, except 18 and 20 pin minimum body length (Dim A).
- The 20 pin end lead shoulder width is a vendor option, either half or full width.



D (R-PDS0-G16)

PLASTIC SMALL OUTLINE



- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.006 (0,15) each side.
- Body width does not include interlead flash. Interlead flash shall not exceed 0.017 (0,43) each side.
- E. Reference JEDEC MS-012 variation AC.



D (R-PDSO-G16)

PLASTIC SMALL OUTLINE



- A. All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
- C. Publication IPC-7351 is recommended for alternate designs.
- D. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC-7525 for other stencil recommendations.
- E. Customers should contact their board fabrication site for solder mask tolerances between and around signal pads.



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